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Title: X-ray detector development at 100 MHz framerate or above

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Intended for: Discussion at DESY on LANL-HIBEF collaboration

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# X-ray detector development

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At 100 MHz framerate or above

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*Los Alamos National Laboratory, Los Alamos, NM 87545*

April 8-9, 2019

Eu-XFEL/DESY, Hamburg, DE

# Outline

## ■ Introduction to the challenges

- MaRIE workshops and community wisdoms
- The state-of-the-art
- Opportunities

## ■ Our approach & progress (enabled by collaborations)

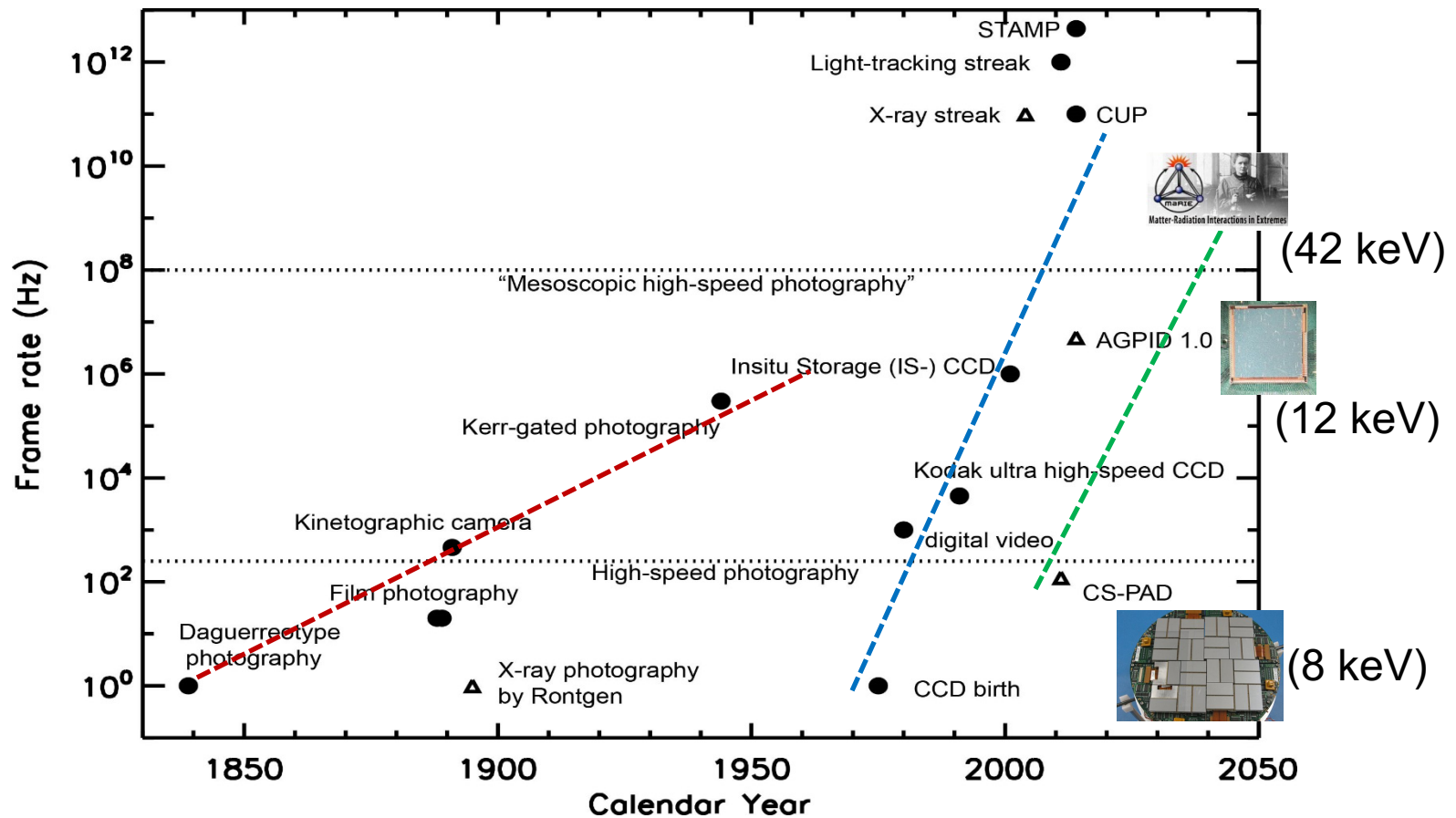
- New Materials
  - Materials Discovery
- New Architectures
  - Pushing silicon architecture to higher speeds
- New data & imaging methods
- Near term applications Laboratory and APS Experimental tests of materials and imaging

## ■ Upcoming activities

- Development and experimental validation where vision and support coincide
- ULITIMA 2020 (jointly with ICHSIP33 ~ San Diego, CA, USA)



# Evolution of high-speed imaging technologies



# The August 2016 workshop surveyed current status And identified future opportunities

**High-energy and Ultrafast X-Ray Imaging Technologies and Applications**  
*A MaRIE workshop showing a light on the future of ultrafast high-energy photon technology*

ACCOMMODATIONS   ABSTRACTS   REGISTRATION   PROGRAM   TRAVEL



**Ultrafast high-energy photon imaging**  
→ ps, GHz & large data

**Local Organizers**

- Michael Stevens
- Zhehui (Jeff) Wang (505) 665-5353

**Meeting Planner**

- Peggy Vigil (505) 867-8448 For logistical purposes and questions

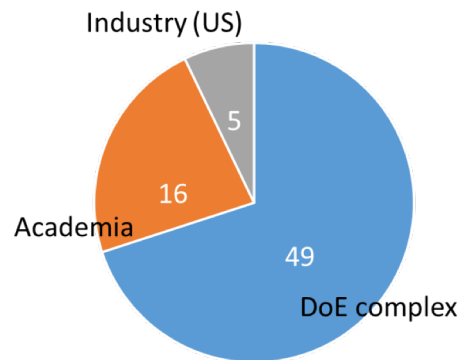
**External Co-Organizers**

- Peter Denes (LBL)
- Sol Gruner (Cornell Univ.)

**High-energy and Ultrafast X-Ray Imaging Technologies and Applications**  
Date: August 2-3, 2016  
Hotel venue: Hilton Santa Fe at Buffalo Thunder

The goal of this workshop is to gather leading experts in the fields related to ultrafast high-energy photon imaging and prioritize the path forward for ultrafast hard x-ray imaging technology development, identify important applications in the next 5-10 years, and establish foundations for near-term R&D collaboration.

This workshop is one in a series being organized by Los Alamos National Laboratory to engage broader scientific community in the MaRIE (Matter-Radiation Interactions in Extremes) development process. MaRIE is the proposed

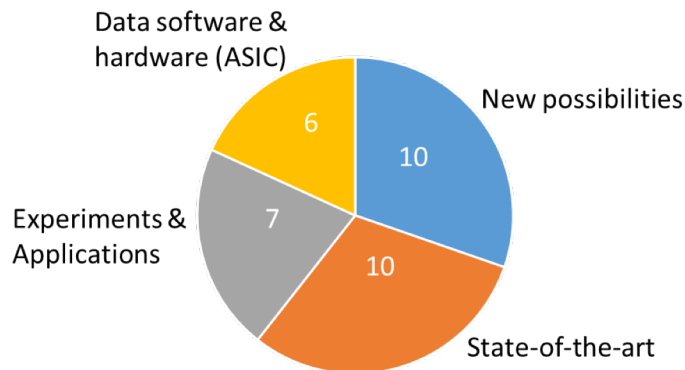


## Ultrafast and High-Energy X-Ray Imaging Technologies & Applications

(August 2-3, 2016, Santa Fe, NM 87506, USA)

### Table of Contents

Executive summary .....	2
Introduction .....	3
Type I & Type II ultrafast and high-energy X-ray imaging technologies .....	3
Charges to the workshop .....	4
Workshop overview .....	4
Workshop findings .....	6
A. The state-of-the-art imaging technologies .....	6
B. Scientific and LANL mission needs .....	7
C. Relations to large data and on-board data processing (ASIC) .....	8
D. Emerging sensor materials and device possibilities .....	9
E. Near-term & long-term ultrafast imaging technologies for HE-XFEL .....	12
Recommendations .....	15
Appendices .....	16
Workshop participants & group photo .....	16
Workshop agenda .....	16
Presentation summaries .....	16
Workshop summaries .....	16



# Two-pronged development process: (Low & High Risk)

Performance	Type I imager	Type II imager
X-ray energy	30 keV	42-126 keV
Frame-rate/inter-frame time	0.5 GHz/2 ns	3 GHz / 300 ps
Number of frames	10	10 - 30
X-ray detection efficiency	above 50%	above 80%
Pixel size/pitch	$\leq 300$ nm	$< 300$ nm
Dynamic range	$10^3$ X-ray photons	$\geq 10^4$ X-ray photons
Pixel format	64 x 64 (scalable to 1 Mpix)	1 Mpix

## MaRIE KPP requirements

ASIC/Data	No. Chan.	Analog bandwidth (GHz)	digital sampling (GHz)	S/N (dB)	Bit Res.	CMOS technol.
PSEC4	6	1.5	15		10.5	IBM 130 nm
"Hawaii chip"	128?	3	20	58 dB/1Vpp	9.4	(TSMC 130 nm)
"Cornell Keck GHz"	384 x 256	0.5				
epixΔ	1M	3			$\geq 8$	TSMC 250 nm

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LANL Hamburg 2019

Z. Wang Slide 5

# Analysis of current performance gaps to requirements points to speed and high-energy efficiency as critical issues

	(>50%) x (>20 keV)	Sensor Speed (<10 ns)	ASIC (>0.1 GHz)	No. of Frames (>10)	Resolution (<250 $\mu\text{m}$ )	Dynamic Range (> $10^3$ )
UXI	< 100 $\mu\text{m}$ Si	-	~ 0.5 GHz	4	25 $\mu\text{m}$	-
pRad2	< 100 $\mu\text{m}$ Si	50 ns	4 MHz	10	40 $\mu\text{m}$	< $10^3$
AGIPD 1.0	500 $\mu\text{m}$ Si	> 10 ns	4.5 MHz	352	200 $\mu\text{m}$	$10^4$
KeckPAD	500 $\mu\text{m}$ Si	> 10 ns	6.5 MHz	8	150 $\mu\text{m}$	> $10^3$
ePix100a	500 $\mu\text{m}$ Si	> 10ns	120 Hz	1	25 $\mu\text{m}$	> $10^3$
EIGER	450 $\mu\text{m}$ Si	> 10 ns	9 kHz	1	75 $\mu\text{m}$	> $10^3$
Ultra UBSi	< 100 $\mu\text{m}$ Si	-	1 GHz	25	7.4 $\mu\text{m}$	< $10^3$
Teledyne Dalsa	< 100 $\mu\text{m}$ Si	-	100 MHz	16	< 50 $\mu\text{m}$	-

(Credit: C. W. Barnes)

# Our vision

- \* Involve materials scientists to develop new photon conversion materials

**“GHz technology”**

- \* Explore new architectures, work with a national collaboration

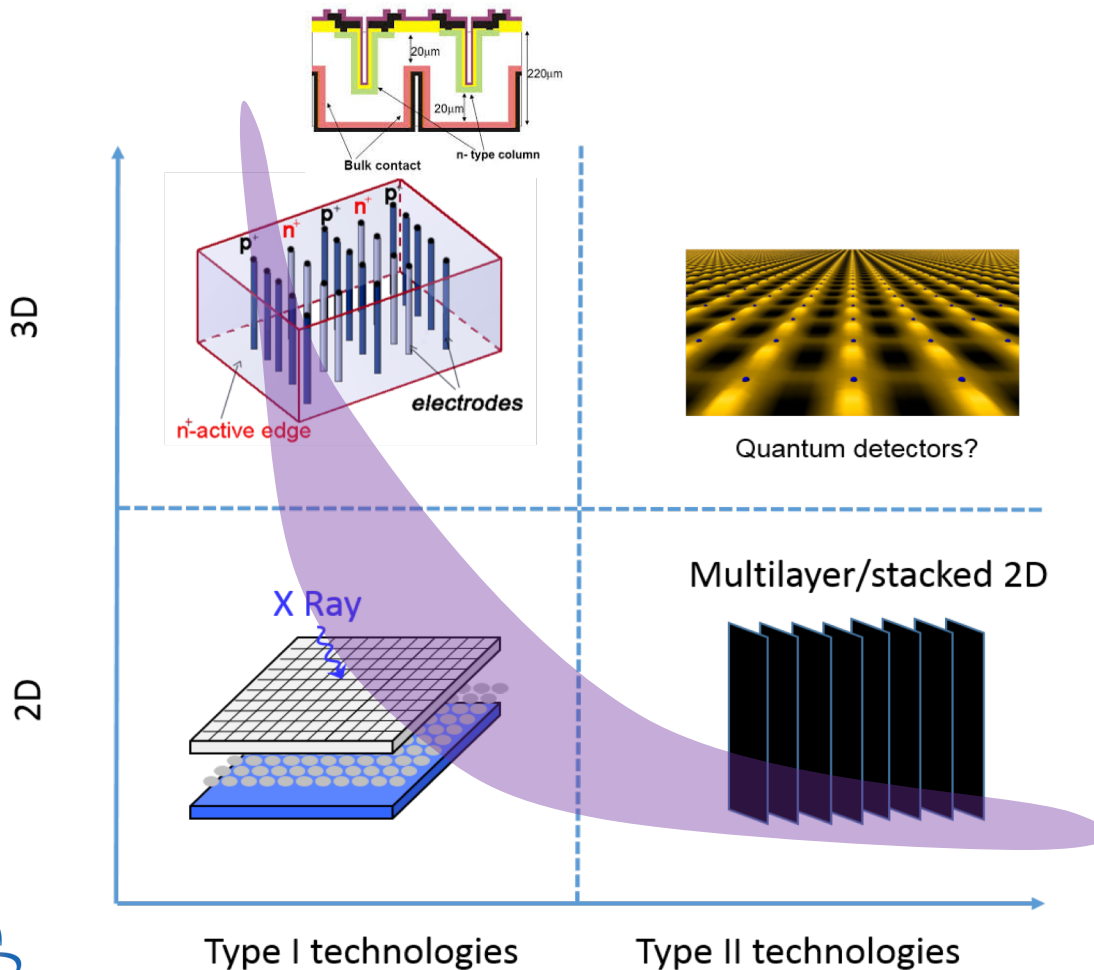
**“100 MHz + technology”**

- \* Data-method boosted hardware development & performance

**“10 MHz technology”**

**We are here**

# 1) There are Structural & Processing Innovations that could be pursued



Material Processes	Features	
Thin film process	novel properties	thin-film
Additive process	Micro-, nano-grains	
Microfluidic process	Versatile nano-particle assembly	nano-
Polymer-assisted fabrication	Versatile nano-particle assembly	nano-
Self-assembly/biological assisted processes	Autonomous	

Existing processes:  
CMOS,  
SOI,  
SiGe.

# MULTI-LAB (NNSA and DOE/SC) TEAM on advancing silicon

- **ANL**

- SYNCHROTRON SOURCE (APS)
- MONOLITHIC DETECTOR TECHNOLOGY (MAPS); MCP & photodetectors benchmark



- **LANL**

- SYSTEM INTEGRATION, NOVEL STRUCTURES
- TESTING & APPLICATIONS (IMAGING METHODS, DATA Handling)

- **LBL**

- ULTRFAST PHOTODETECTORS



- **SNL**

- CHIPS/ROICs, DESIGNs



Sandia  
National  
Laboratories

~\$20M TPC over 5 years to  
deliver 100 MHz framing camera  
for use at DCS@APS or LCLS

- **SLAC**

- LCLS & OTHER FACILITIES
- ASIC DESIGNs, HYBRID CONCEPTS



NATIONAL  
ACCELERATOR  
LABORATORY



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Z. Wang Slide 9



# UMA collaboration

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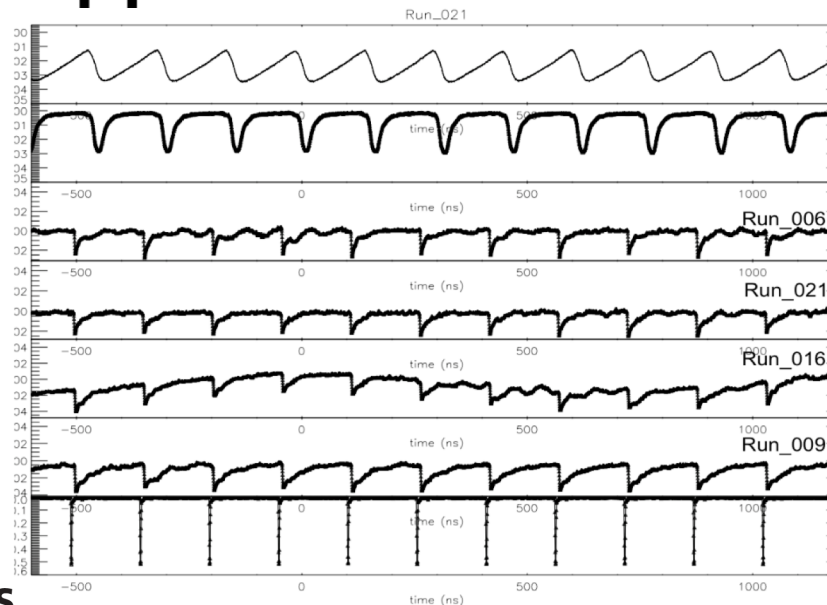
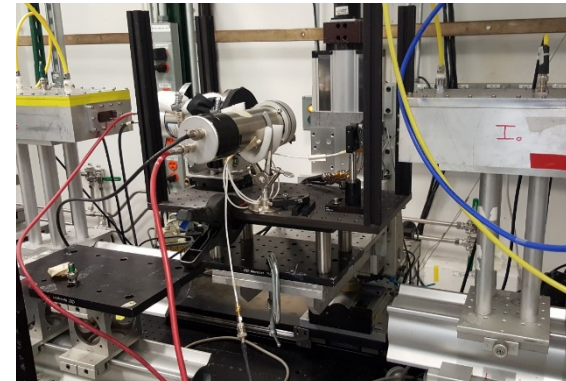
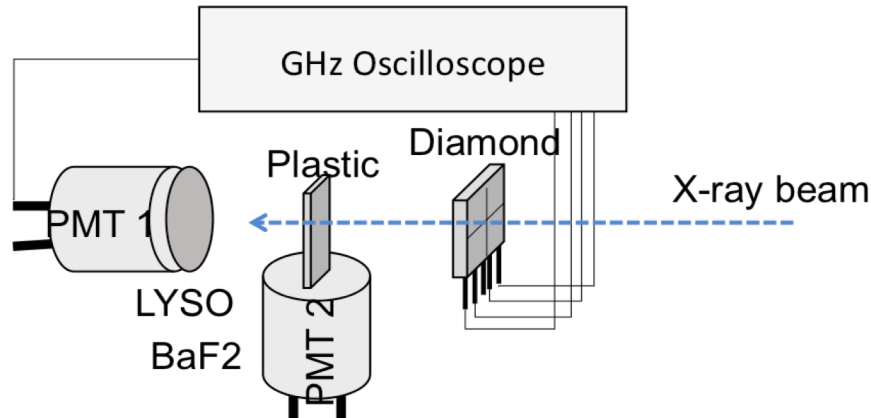
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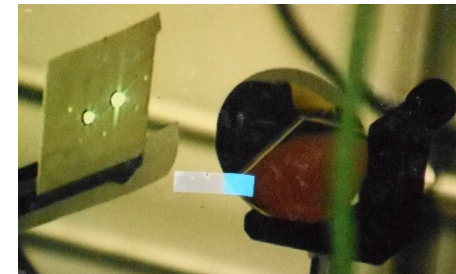
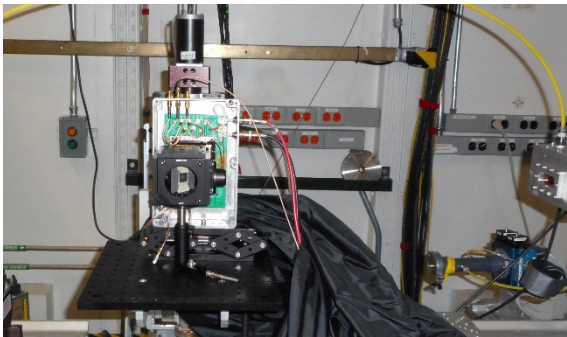
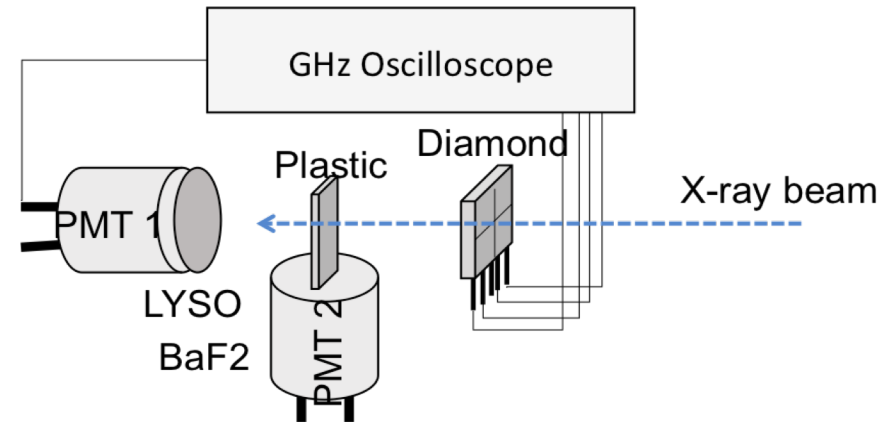
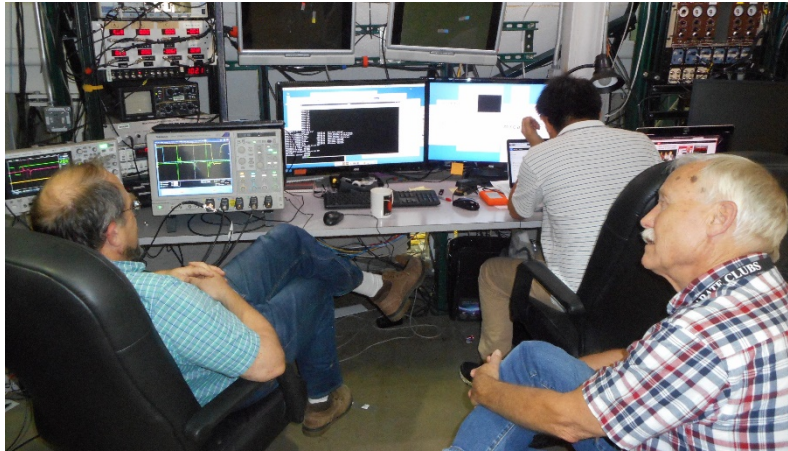
# APS Experiment (Feb. 2018)



LYSO + PMT 1  
Fast plastic + PMT 2  
Diamond (Quadrant A)  
Diamond (Quadrant B)  
Diamond (Quadrant C)  
Diamond (Quadrant D)  
APS timing pulses

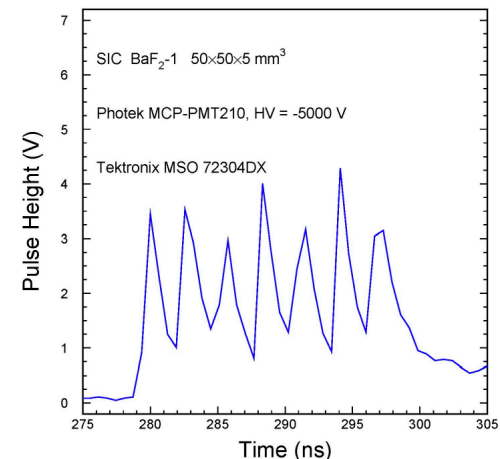
J. Xie et al,  
NIMA (2019)

# APS Experiment (Jul. 2018)



# 12 fast Scintillators tested

			Detector			LYSO+PMT1		Plastic+PMT2		Diamond		
			Amplitude			20.9 ± 0.4 mV		25.8 ± 0.4 mV		1.9 ± 0.2 mV		
	BaF <sub>2</sub>	BaF <sub>2</sub> (:Y)	Rise time			18.4 ± 0.6 ns		12.4 ± 0.2 ns		2.0 ± 0.2 ns		
			Decay time			80.7 ± 1.8 ns		26.7 ± 0.9 ns		28.3± 6.2 ns		
Density (g/cm <sup>3</sup> )	4.89	4.89										
Melting points (°C)	1280	1280	1975	1870	1940	1725	2050	2060	1870	1850	1930	2070
X <sub>0</sub> (cm)	2.03	2.03	2.51	2.77	3.53	2.51	1.14	1.45	2.77	1.63	1.37	3.10
R <sub>M</sub> (cm)	3.1	3.1	2.28	2.4	2.76	2.20	2.07	2.15	2.4	2.20	2.01	2.93
λ <sub>i</sub> (cm)	30.7	30.7	22.2	22.4	25.2	20.9	20.9	20.6	22.4	21.5	19.5	27.8
Z <sub>eff</sub>	51.6	51.6	27.7	31.9	30	28.1	64.8	60.3	31.9	51.8	58.6	33.3
dE/dX (MeV/cm)	6.52	6.52	8.42	8.05	7.01	8.82	9.55	9.22	8.05	8.96	9.82	6.57
λ <sub>peak</sub> <sup>a</sup> (nm)	300 220	300 220	380	350	350	380	420	520	370	540	385	420
Refractive Index <sup>b</sup>	1.50	1.50	2.1	1.96	1.87	1.97	1.82	1.84	1.96	1.92	1.94	1.78
Normalized Light Yield <sup>a,c</sup>	42 4.8	1.7 4.8	6.6 <sup>d</sup>	0.19 <sup>d</sup>	0.36 <sup>d</sup>	6.5 0.5	100	35 <sup>e</sup> 48 <sup>e</sup>	9 32	115	16 15	80
Total Light yield (ph/MeV)	13,000	2,000	2,000 <sup>d</sup>	57 <sup>d</sup>	110 <sup>d</sup>	2,100	30,000	25,000 <sup>e</sup>	12,000	34,400	10,000	24,000
Decay time <sup>a</sup> (ns)	600 0.6	600 0.6	<1	1.5	4	148 6	40	820 50	191 25	53	1485 36	75
LY in 1 <sup>st</sup> ns (photons/MeV)	1200	1200	610 <sup>d</sup>	28 <sup>d</sup>	24 <sup>d</sup>	43	740	240	391	640	125	318
40 keV Att. Leng. (1/e, mm)	0.106	0.106	0.407	0.314	0.439	0.394	0.185	0.251	0.314	0.319	0.214	0.334

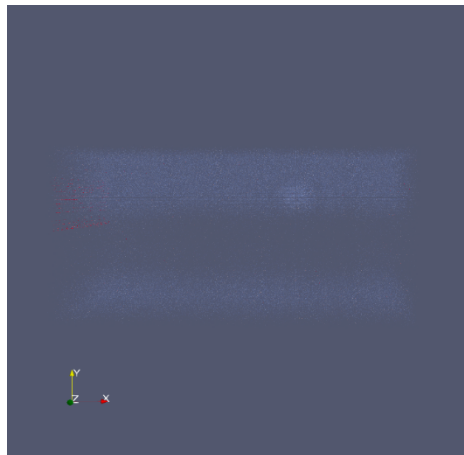
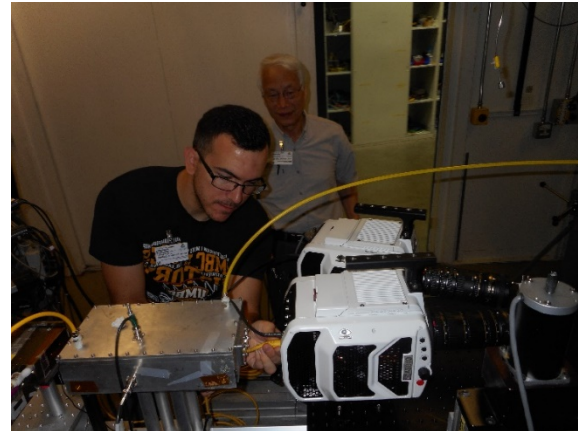


Hybrid mode  
2.83 ns bunch spacing

# High-energy X-ray Ghost imaging (*preliminary*)



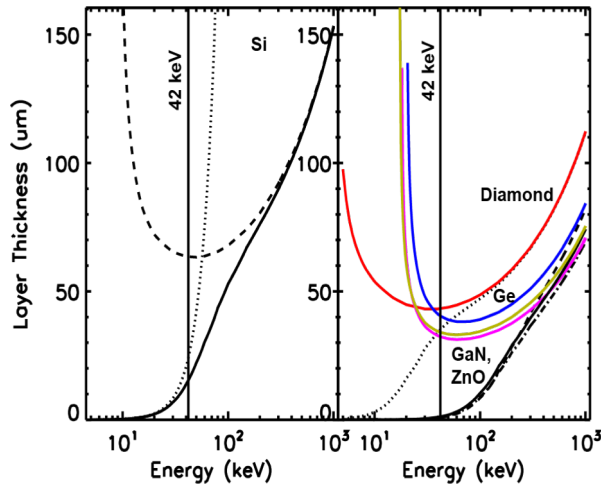
Primary beam



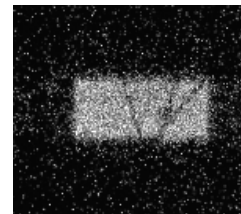
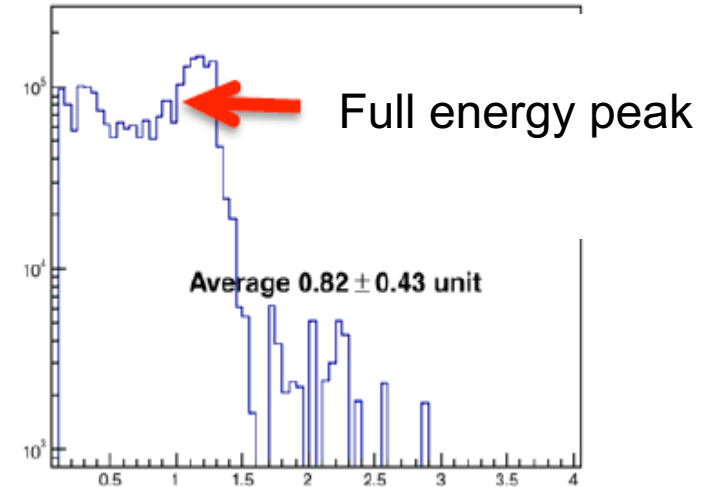
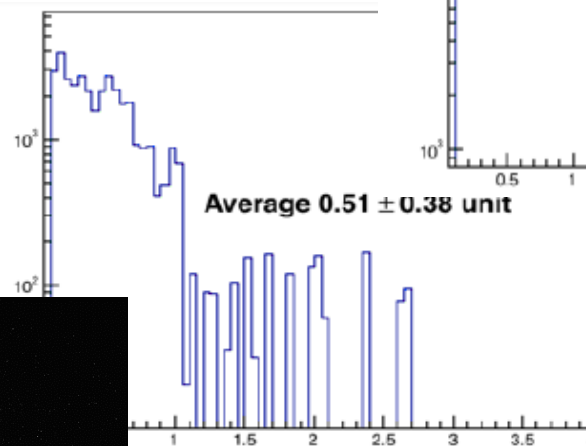
(< 20 um possible)



# Silicon camera characterization

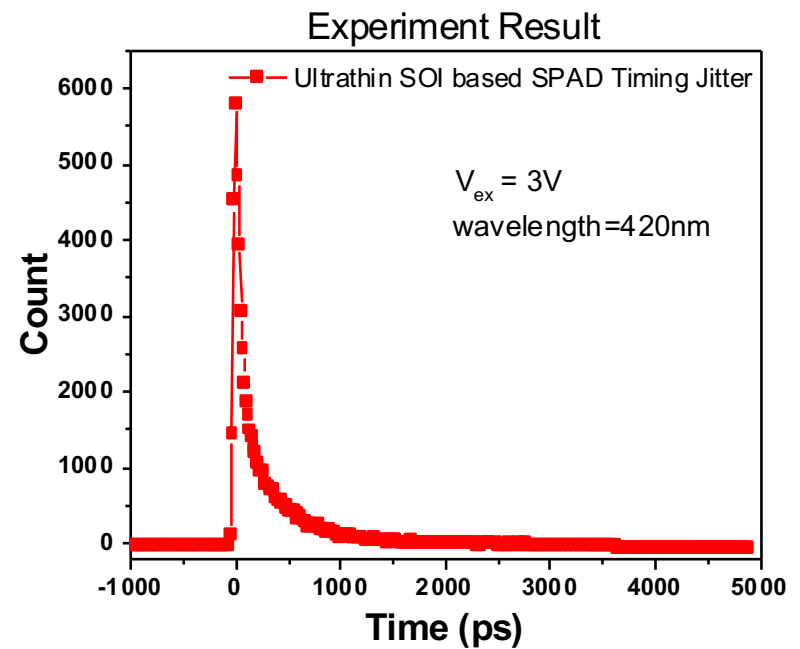
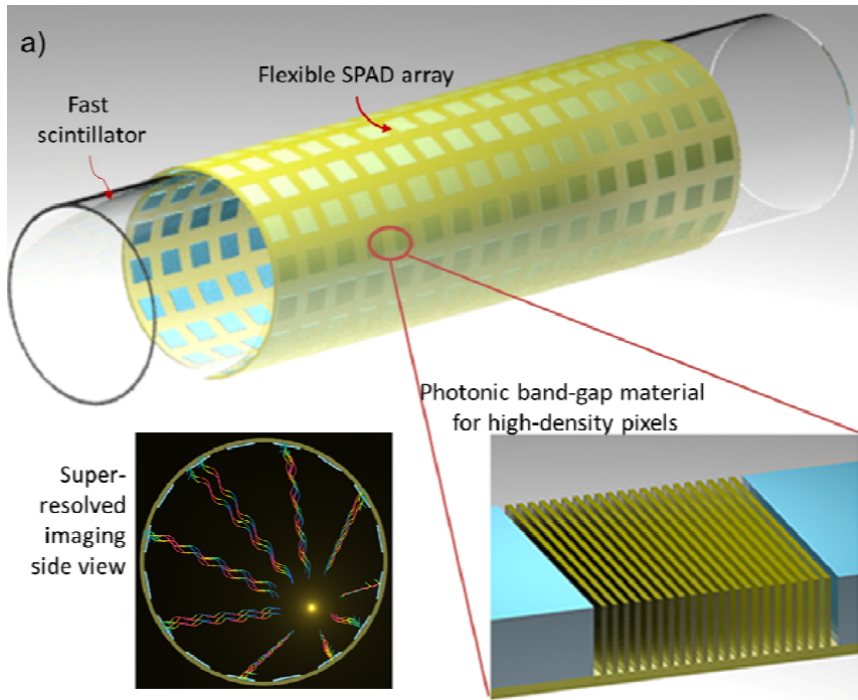


Wang *JINST* 10 (2015) C12013



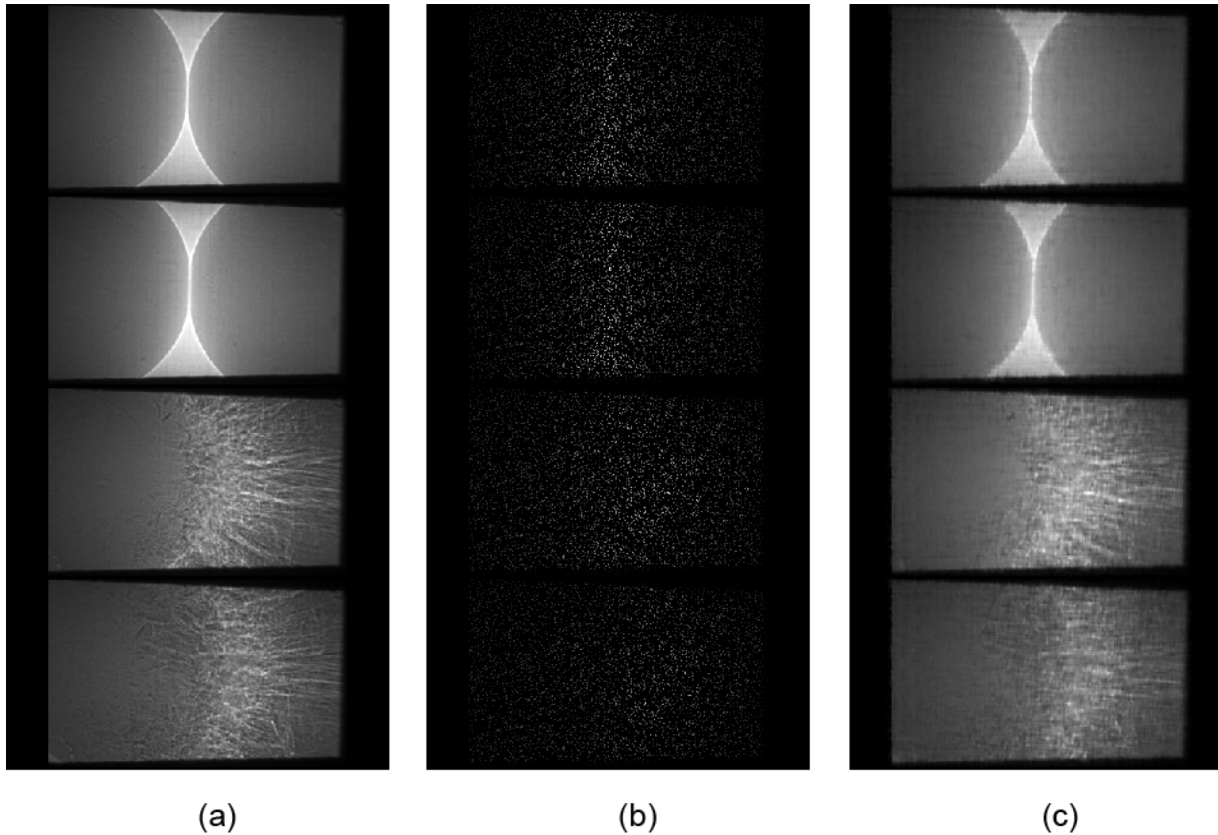
(<10 um resolution)

# SSAP collaboration –Univ. Wisconsin Madison



### 3) New data methods like Sparse X-ray imaging can make good images with fewer photons

Wang et al, *JINST* 13 (2018) C01035



# UMA → UDA collaboration



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April 2019 Z. Wang Slide 18



# We continue to interact, learn from, and collaborate with the best detector teams in the world



ULITIMA2020  
+ ICHSIP33

# Acknowledgement

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J. Bohon



O. Iaroshenko



X. Li



Y. Sechrest

# Summary

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- **Ultrafast imaging technology development requires interdisciplinary approach**
- **Data methods can potentially accelerate the development of ultrafast high-energy X-ray imaging technology**
  - For data & by Data
- **A multi-institution & multi-disciplinary team in place**
  - New collaborations in hardware & applications welcome!